Application/Control No. 09/680,054 Notice of References Cited Examiner Brook Kebede Applicant(s)/Patent Under Reexamination NAKAMURA ET AL. Art Unit Page 1 of 1

U.S. PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Name | Classification |
|----------|---|---|-----------------|------------------|----------------|
| | Α | US-6,319,742 | 11-2001 | Hayashi et al. | 117/952 |
| | В | US-6,323,053 | 11-2001 | Nishikawa et al. | 438/46 |
| | С | US-6,325,850 | 12-2001 | Beaumont et al. | 117/95 |
| | D | US-6,326,638 | 12-2001 | Kamiyama et al. | 257/103 |
| | Ε | US-6,335,546 | 01-2002 | Tsuda et al. | 257/94 |
| | F | US-6,337,223 | 01-2002 | Kim et al. | 438/42 |
| | G | US-6,355,541 | 03-2002 | Holland et al. | 438/459 |
| | Н | US-6,362,016 | 03-2002 | Funato et al. | 257/79 |
| | | US- | | | |
| | J | US- | | | |
| | К | US- | | | |
| | L | US- | | | |
| \vdash | М | US- | | | |

FOREIGN PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Country | Name | Classification |
|---|---|--|-----------------|---------|------------------|----------------|
| | N | JP 2000223417 A | 08-2000 | Japan | Tomioka, Satoshi | H01L 21/205 |
| | 0 | | | | | |
| | Р | | | | | |
| | Q | | | | | |
| | R | | | | | |
| | s | | | | | |
| | T | | | | | |

NON-PATENT DOCUMENTS

| | NON-FAILNI DOCUMENTO | | | | | | |
|---|----------------------|---|--|--|--|--|--|
| * | | Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages) | | | | | |
| | υ | Growth mechanism of GaN on sapphire with AlN buffer by MOVPE, Journal of Crystal Growth, 115, pp 628-633 (1991),. | | | | | |
| | ٧ | Yu et al., Study of the epitaxial-lateral-overgrowth (ELO) process for GaN on sapphire, Journal of Crystal Growth, 195 pp 333-339 (1998). | | | | | |
| | w | | | | | | |
| | х | | | | | | |

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.